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## BIB DATA SHEET

CONFIRMATION NO. 3468

SERIAL NUMBER	FILING or 371(c) DATE	CLASS	GROUP ART UNIT	ATTORNEY DOCKET NO.		
10/659,748	09/11/2003	438	2894	031140		
<b>RULE</b>						
<b>APPLICANTS</b> Manabu Nakamura, Aizuwakamatsu, JAPAN; Hiroyuki Nansei, Aizuwakamatsu, JAPAN; Kentaro Sera, Aizuwakamatsu, JAPAN; Masahiko Higashi, Aizuwakamatsu, JAPAN; Yukihiro Utsuno, Aizuwakamatsu, JAPAN; Hideo Takagi, Aizuwakamatsu, JAPAN; Tatsuya Kajita, Aizuwakamatsu, JAPAN;						
<b>** CONTINUING DATA *****</b> <b>** FOREIGN APPLICATIONS *****</b> JAPAN 2002-273625 09/19/2002 <b>** IF REQUIRED, FOREIGN FILING LICENSE GRANTED **</b> 12/03/2003						
Foreign Priority claimed <input checked="" type="checkbox"/> Yes <input type="checkbox"/> No 35 USC 119(a-d) conditions met <input checked="" type="checkbox"/> Yes <input type="checkbox"/> No Verified and Acknowledged <u>/BRADLEY SMITH/</u> Examiner's Signature		<input type="checkbox"/> Met after Allowance Initials	<b>STATE OR COUNTRY</b> JAPAN	<b>SHEETS DRAWINGS</b> 8	<b>TOTAL CLAIMS</b> 18	<b>INDEPENDENT CLAIMS</b> 1
<b>ADDRESS</b> WESTERMAN, HATTORI, DANIELS & ADRIAN, LLP 1250 CONNECTICUT AVENUE, NW SUITE 700 WASHINGTON, DC 20036 UNITED STATES						
<b>TITLE</b> Method of manufacturing semiconductor device having gate or tunnel insulation film						
<b>FILING FEE RECEIVED</b> 900	FEES: Authority has been given in Paper No. _____ to charge/credit DEPOSIT ACCOUNT No. _____ for following:			<input type="checkbox"/> All Fees <input type="checkbox"/> 1.16 Fees (Filing) <input type="checkbox"/> 1.17 Fees (Processing Ext. of time) <input type="checkbox"/> 1.18 Fees (Issue) <input type="checkbox"/> Other _____ <input type="checkbox"/> Credit		